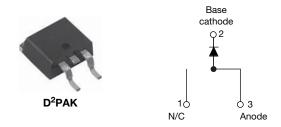


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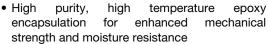
High Performance Schottky Rectifier, 20 A



PRODUCT SUMMARY							
I _{F(AV)}	20 A						
V_{R}	35 V, 40 V, 45 V						
V _F at I _F	0.51 V						
I _{RM}	105 mA at 125 °C						
T _J max.	150 °C						
E _{AS}	27 mJ						
Package	TO-263AB (D ² PAK)						
Diode variation	Single die						

FEATURES

- 150 °C T_J operation
- Low forward voltage drop
- High frequency operation





- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: For definitions of compliance please see <u>www.vishav.com/doc?99912</u>

DESCRIPTION

The VS-20TQ... Schottky rectifier series has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS										
SYMBOL	CHARACTERISTICS	VALUES	UNITS							
I _{F(AV)}	Rectangular waveform	20	Α							
V _{RRM}	Range	35 to 45	V							
I _{FSM}	t _p = 5 μs sine	1800	Α							
V _F	20 A _{pk} , T _J = 125 °C	0.51	V							
T _J	Range	-55 to 150	°C							

VOLTAGE RATINGS								
PARAMETER	SYMBOL	VS-20TQ035S-M3	VS-20TQ040S-M3	VS-20TQ045S-M3	UNITS			
Maximum DC reverse voltage	V_R	35	40	45	W			
Maximum working peak reverse voltage	V_{RWM}	ან	40	45	V			

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST COND	VALUES	UNITS				
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 116 °C	20					
Maximum peak one cycle		5 μs sine or 3 μs rect. pulse	Following any rated load	1800	Α			
non-repetitive surge current See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	condition and with rated V _{RRM} applied	400				
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 ^{\circ}\text{C}$, $I_{AS} = 4 \text{A}$, $L = 3.40 \text{m}$	27	mJ				
Repetitive avalanche current	I _{AR}	Current decaying linearly to zer Frequency limited by T_J maxim	4	Α				



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ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST COND	VALUES	UNITS				
Maximum forward voltage drop See fig. 1		20 A	T _{.1} = 25 °C	0.57	V			
	V _{FM} ⁽¹⁾	40 A	1J=25 C	0.73				
	VFM (*)	20 A	T _{.1} = 125 °C	0.51				
		40 A	1] = 125 0	0.67				
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	V _B = Rated V _B	2.7	mA			
See fig. 2	'RM\''	T _J = 125 °C	VR = nateu VR	105	IIIA			
Maximum junction capacitance	C _T	$V_R = 5 V_{DC}$ (test signal range	100 kHz to 1 MHz), 25 °C	1400	pF			
Typical series inductance	L _S	Measured lead to lead 5 mm	8.0	nH				
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs				

Note

 $^{^{(1)}\,}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range		T _J , T _{Stg}		-55 to 150	°C			
Maximum thermal resistance, junction to case		R _{thJC}	DC operation See fig. 4	1.50	°C/W			
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50				
Approximate weight				2	g			
Approximate weight				0.07	OZ.			
Mounting torque	minimum			6 (5)	kgf · cm			
Mounting torque	maximum			12 (10)	(lbf · in)			
Marking device			Case style D ² PAK		035S 040S 045S			

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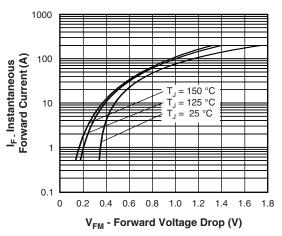


Fig. 1 - Maximum Forward Voltage Drop Characteristics

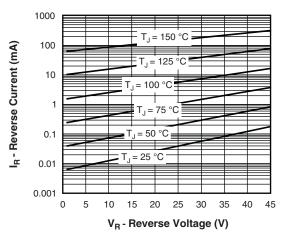


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

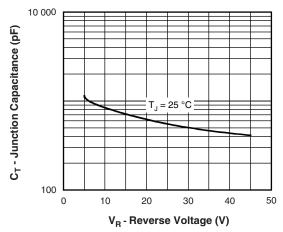


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

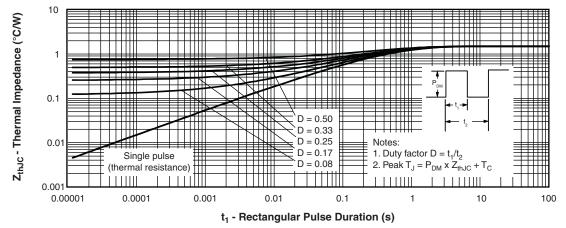


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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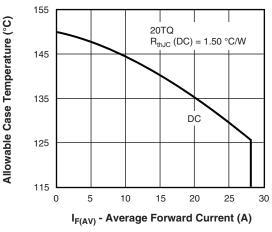


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

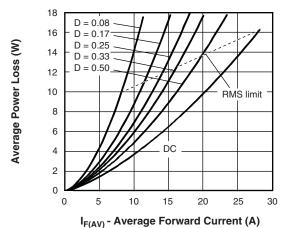
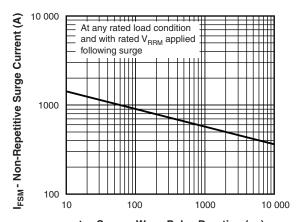


Fig. 6 - Forward Power Loss Characteristics



 t_{p} - Square Wave Pulse Duration ($\mu \text{s})$

Fig. 7 - Maximum Non-Repetitive Surge Current

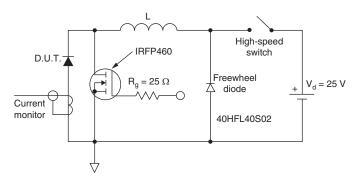
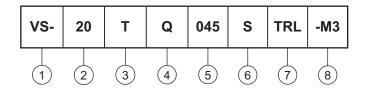


Fig. 8 - Unclamped Inductive Test Circuit

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ORDERING INFORMATION TABLE

Device code



Vishay Semiconductors product

Current rating (20 A)

Package: T = TO-220

Schottky "Q" series

035 = 35 V 040 = 40 VVoltage ratings 045 = 45 V

 $S = D^2PAK$

• None = Tube

• TRL = Tape and reel (left oriented)

• TRR = Tape and reel (right oriented)

8 -M3 = Halogen-free, RoHS-compliant and termination lead (Pb)-free

ORDERING INFORMATION										
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION							
VS-20TQ035S-M3	50	1000	Antistatic plastic tubes							
VS-20TQ035STRR-M3	800	800	13" diameter reel							
VS-20TQ035STRL-M3	800	800	13" diameter reel							
VS-20TQ040S-M3	50	1000	Antistatic plastic tubes							
VS-20TQ040STRR-M3	800	800	13" diameter reel							
VS-20TQ040STRL-M3	800	800	13" diameter reel							
VS-20TQ045S-M3	50	1000	Antistatic plastic tubes							
VS-20TQ045STRR-M3	800	800	13" diameter reel							
VS-20TQ045STRL-M3	800	800	13" diameter reel							

LINKS TO RELATED DOCUMENTS						
Dimensions <u>www.vishay.com/doc?95046</u>						
Part marking information	www.vishay.com/doc?95444					
Packaging information	www.vishay.com/doc?95032					



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D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	ETERS	INC	INCHES		NOTES	SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOIES	NOTES	STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100) BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB



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